NSN 5961-00-982-8890

No Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-982-8890 **Inclosure Material:** Metal **Overall Length:** Between 0.140 inches and 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** Between 0.290 inches and 0.370 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** Between 0.190 inches and 0.210 inches **Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 7.0 emitter to base voltage, dc all transistor and 60.0 collector to emitter voltage, dc all transistor and 80.0 collector to base voltage, dc all transistor **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 600.0 milliwatts small-signal input power, common-collector all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Internal junction configuration transistor npn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**